

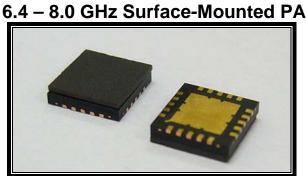


### **FEATURES**

- 6.4 8.0 GHz Operating Frequency Range
- 32.5dBm Output Power at 1dB Compression
- 15.0 dB Typical Small Signal Gain
- -40dBc OIMD3 @Each Tone Pout 22.5dBm

### **APPLICATIONS**

- Point-to-point and point-to-multipoint radio
- Military Radar Systems





Caution! ESD sensitive device.

## ELECTRICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C, 50 ohm, VDD=10V, IDQ=1000mA)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
F	Operating Frequency Range	6.4		8.0	GHz
P1dB	Output Power at 1dB Gain Compression	31.5	32.5		dBm
Gss	Small Signal Gain	13.0	15.0		dB
OIMD3	Output 3 <sup>rd</sup> Order Intermodulation Distortion @∆f=10MHz, Each Tone Pout 22.5dBm		-40	-37	dBc
Input RL	Input Return Loss		-15	-10	dB
Output RL	Output Return Loss		-6		dB
ldss	Saturate Drain Current V <sub>DS</sub> =3V, V <sub>GS</sub> =0V		1680		mA
V <sub>DD</sub>	Power Supply Voltage		10		V
Rth	Thermal Resistance <sup>1</sup>		7		°C/W
Tb	Operating Base Plate Temperature	-35		+85	°C

# ABSOLUTE MAXIMUM RATINGS FOR CONTINUOUS OPERATION<sup>2,3</sup>

SYMBOL	CHARACTERISTIC	CONTINUOUS
$V_{ extsf{DS}}$	Drain to Source Voltage	10 V
$V_{GS}$	Gate to Source Voltage	-4 V
$I_{DD}$	Drain Current	ldss
$I_{GSF}$	Forward Gate Current	35mA
$P_{IN}$	Input Power	@ 3dB compression
$T_CH$	Channel Temperature	150°C
$T_{STG}$	Storage Temperature	-65/150°C
$P_T$	Total Power Dissipation	17W

<sup>1.</sup> R<sub>th</sub> is mounting dependent. Measured result when used with Excelics recommended evaluation board. Adequate heat sinking recommended.

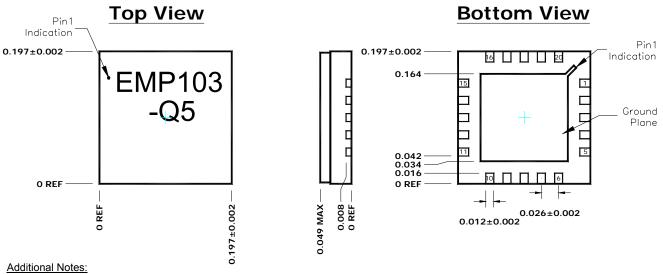
<sup>2.</sup> Operating the device beyond any of the above rating may result in permanent damage.

<sup>3.</sup> Bias conditions must also satisfy the following equation  $V_{DS}*I_{DS} < (T_{CH} - T_{HS})/R_{TH}$ ; where  $T_{HS}$  = ambient temperature

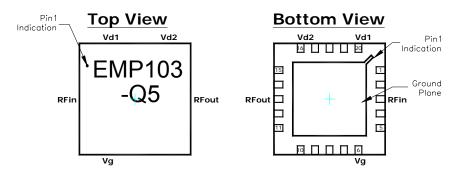


# 6.4 - 8.0 GHz Surface-Mounted PA

### **CHIP OUTLINE AND PIN ASSIGNMENT**



- Ground Plane must be soldered to PCB RF ground
  - 2) All dimensions are in inches3) Refer to Excelics application notes on QFNs for further guidelines
  - 4) Pin Assignment:

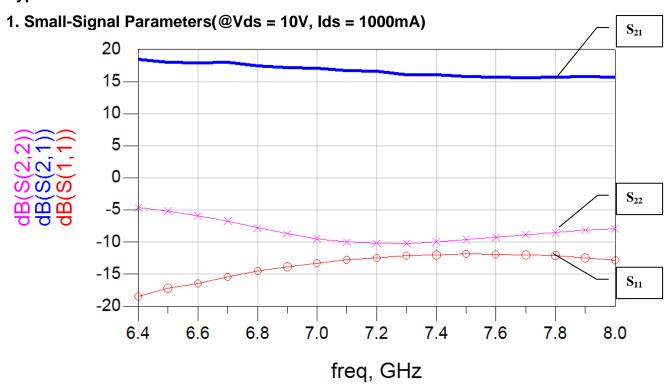


Pin	Assignment
1, 2, 4, 5	NC
3	$RF_in$
6	$V_{q}$
7, 8, 9, 10, 11, 12, 14, 15	NČ
13	$RF_out$
16	$V_{d2}$
17, 18, 19	NC
20	$V_{d1}$

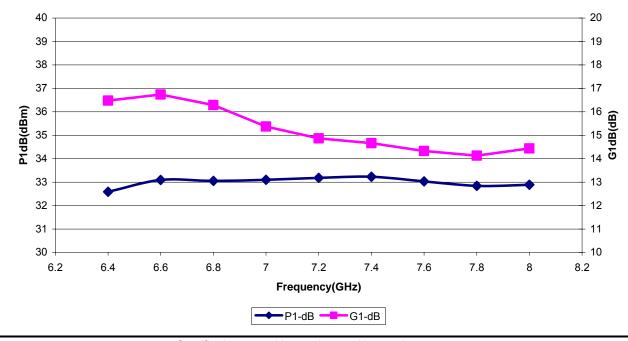


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## **Typical Performance:**



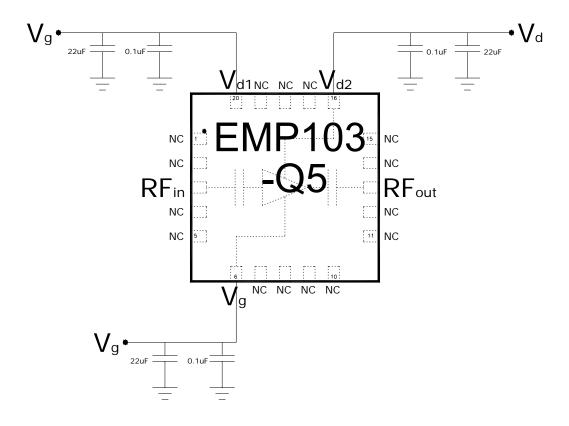
# 2. P1-dB & G1-dB (@Vds = 10V, lds = 1000mA)





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## **Recommended Circuit Schematic:**



### Notes:

- External bypass capacitors should be placed as close to the package as possible.
- Dual biasing sequence required: 2)
  - a. Turn-on Sequence: Apply  $V_g$  = -2.5V, followed by  $V_d$  = 10V, lastly increase  $V_g$  until required  $I_{dq}$  b. Turn-off Sequence: Turn off  $V_d$ , followed by  $V_g$
- 3) Demonstration board available upon request.

